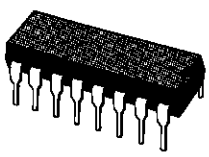
SGS-THOMSON MICROELECTRONICS

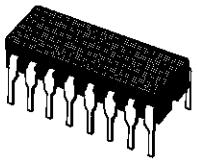
M54HC4017
M74HC4017

DECADE COUNTER/DIVIDER

- HIGH SPEED
  t_{PD} = 21 ns (typ.) AT V_{CC} = 5V
- LOW POWER DISSIPATION
  I_{CC} = 4 µA (MAX.) AT T_A = 25 °C
- HIGH NOISE IMMUNITY
  $V_{NIH} = V_{NIL}$ = 28 % V_{CC} (MIN.)
- OUTPUT DRIVE CAPABILITY
  10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
  $|I_{OH}| = I_{OL}$ = 4 mA (MIN.)
- BALANCED PROPAGATION DELAYS
  $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
  V_{CC} (OPR) = 2 V TO 6 V
- PIN AND FUNCTION COMPATIBLEWITH 4017B



B1R
(Plastic Package)



F1R
(Ceramic Package)

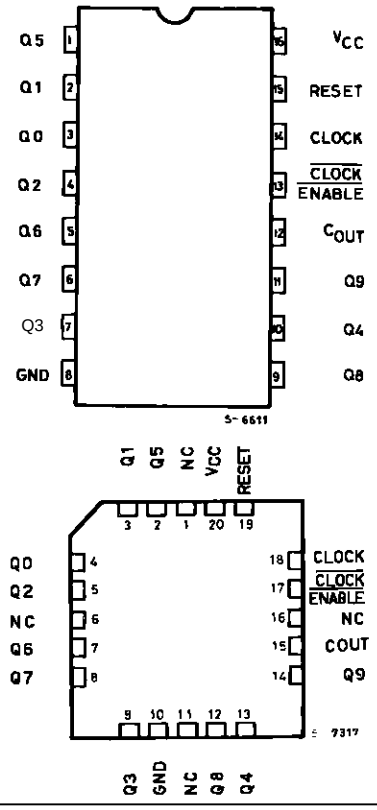
M1R
(Micro Package)

C1R
(Chip Carrier)

ORDER CODES :

M54HC4017F1R M74HC4017M1R
M74HC4017B1R M74HC4017C1R

PIN CONNECTIONS (top view)



NC =
No Internal
Connection

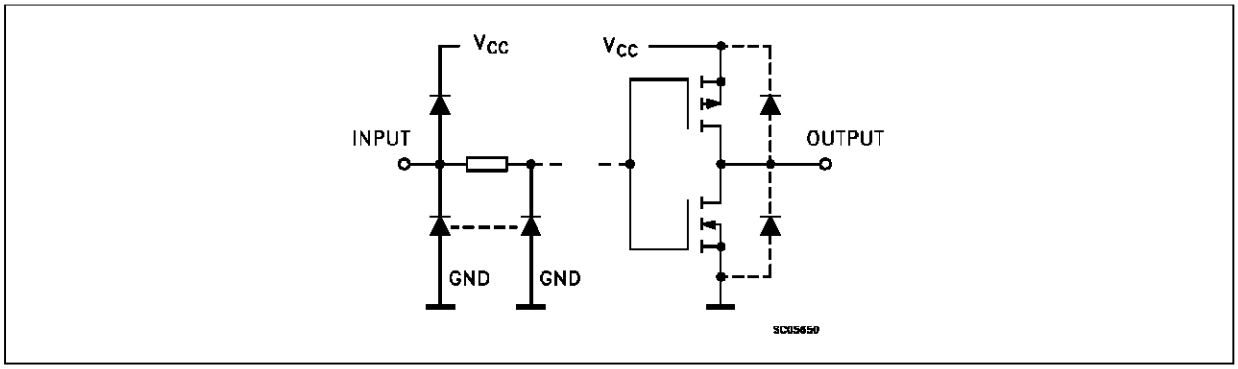
DESCRIPTION

The M54/74HC4017 is a high speed CMOS DECADE COUNTER/DIVIDER fabricated in silicon gate C2MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption.

The M54/74HC4017 is a 5-stage Johnson counter with 10 decoded outputs. Each of the decoded outputs is normally low and sequentially goes high on the low to high transition of the clock input. Each output stays high for one clock period of the 10 clock period cycle. The CARRY output goes low to high after OUTPUT 10 goes low, and can be used in conjunction with the CLOCK ENABLE to cascade several stages.

The CLOCK ENABLE input disables counting when in the high state. A RESET input is also provided which when taken high sets all the decoded outputs low.

INPUT AND OUTPUT EQUIVALENT CIRCUIT

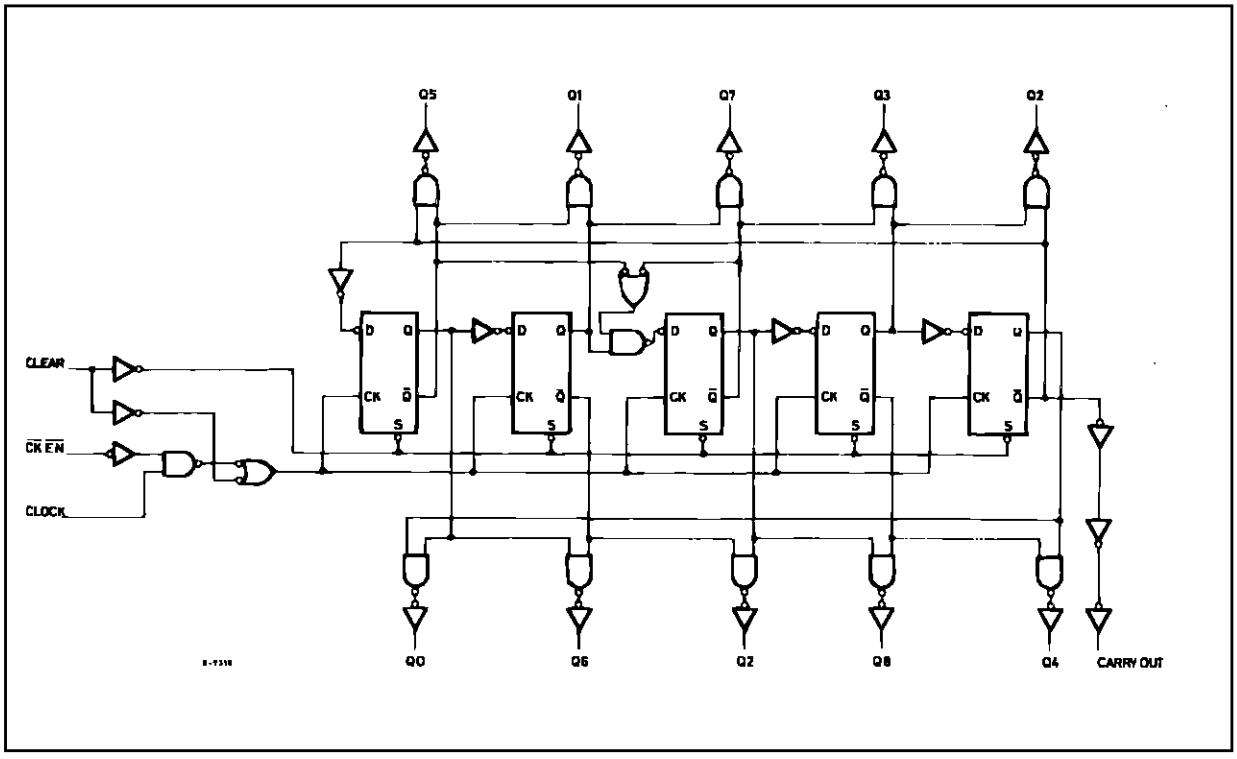


TRUTH TABLE

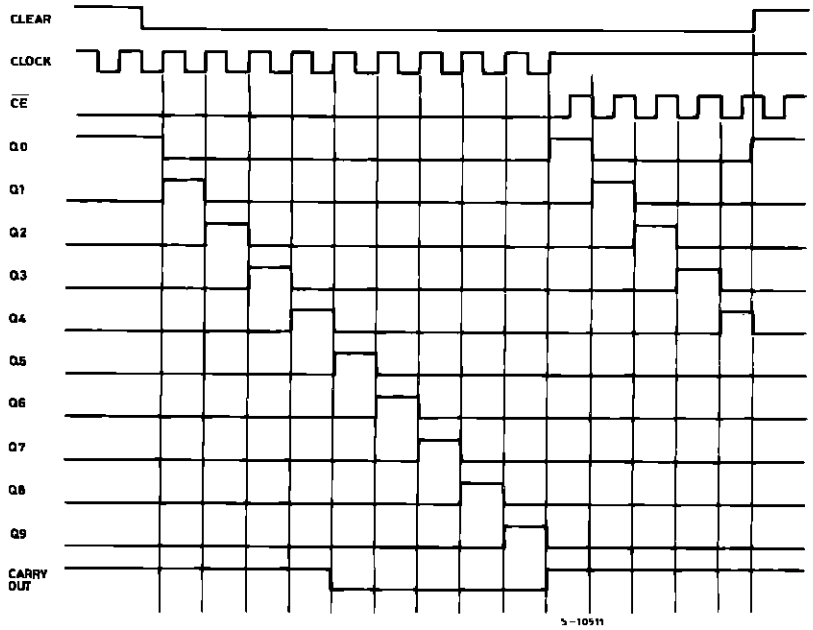
CLOCK	CLOCK ENABLE	CLEAR	DECODE OUTPUT (H)
X	X	H	QO
L	X	L	Qn
X	H	L	Qn
⌐¯	L	L	Qn + 1
¯⌐	L	L	Qn
H	⌐¯	L	Qn
H	¯⌐	L	Qn + 1

X: DON'T CARE
Qn : NO CHANGE

LOGIC DIAGRAM



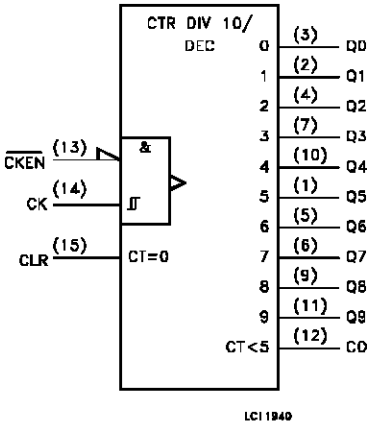
TIMING DIAGRAM



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
3, 2, 4, 7, 10, 1, 5, 6, 9, 11	Q0 to Q9	Decoded Outputs
12	C_{OUT}	Carry Output (Active LOW)
13	$\overline{CKEN}$	Clock Enable Input (Active LOW)
14	CLOCK	Clock Input (LOW to HIGH, Edge-triggered)
15	RESET	Master Reset Input (Active HIGH)
8	GND	Ground (0V)
16	V_{CC}	Positive Supply Voltage

IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to V_{CC} + 0.5	V
V_O	DC Output Voltage	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
(*) 500 mW: ≅ 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V_{CC}	Supply Voltage		2 to 6	V
V_I	Input Voltage		0 to V_{CC}	V
V_O	Output Voltage		0 to V_{CC}	V
T_{op}	Operating Temperature: **M54HC** Series **M74HC** Series		-55 to +125 -40 to +85	°C °C
t_r, t_f	Input Rise and Fall Time	V_{CC} = 2 V	0 to 1000	ns
		V_{CC} = 4.5 V	0 to 500	
		V_{CC} = 6 V	0 to 400	

DC SPECIFICATIONS

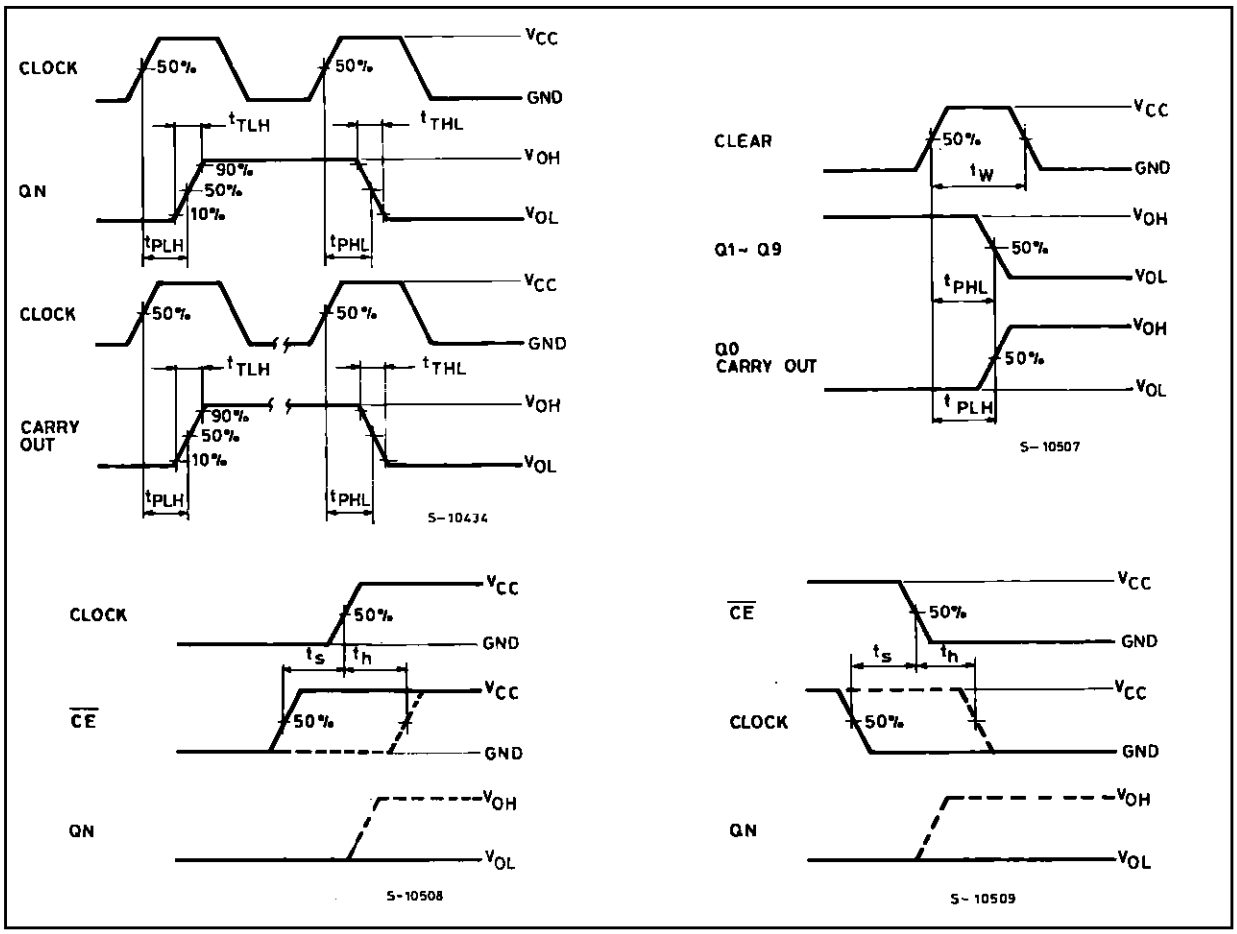
Symbol	Parameter	Test Conditions			Value							Unit
		V_{CC} (V)			T_A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.0			1.5			1.5		1.5		V
		4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
V_{IL}	Low Level Input Voltage	2.0					0.5		0.5		0.5	V
		4.5					1.35		1.35		1.35	
		6.0					1.8		1.8		1.8	
V_{OH}	High Level Output Voltage	2.0	V_I = V_{IH} or V_{IL}	I_O=-20 µA	1.9	2.0		1.9		1.9		V
		4.5			4.4	4.5		4.4		4.4		
		6.0			5.9	6.0		5.9		5.9		
		4.5		I_O=-4.0 mA	4.18	4.31		4.13		4.10		
		6.0		I_O=-5.2 mA	5.68	5.8		5.63		5.60		
V_{OL}	Low Level Output Voltage	2.0	V_I = V_{IH} or V_{IL}	I_O= 20 µA		0.0	0.1		0.1		0.1	V
		4.5				0.0	0.1		0.1		0.1	
		6.0				0.0	0.1		0.1		0.1	
		4.5		I_O= 4.0 mA		0.17	0.26		0.33		0.40	
		6.0		I_O= 5.2 mA		0.18	0.26		0.33		0.40	
I_I	Input Leakage Current	6.0	V_I = V_{CC} or GND				±0.1		±1		±1	µA
I_{CC}	Quiescent Supply Current	6.0	V_I = V_{CC} or GND				4		40		80	µA

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input $t_r = t_f$ = 6 ns)

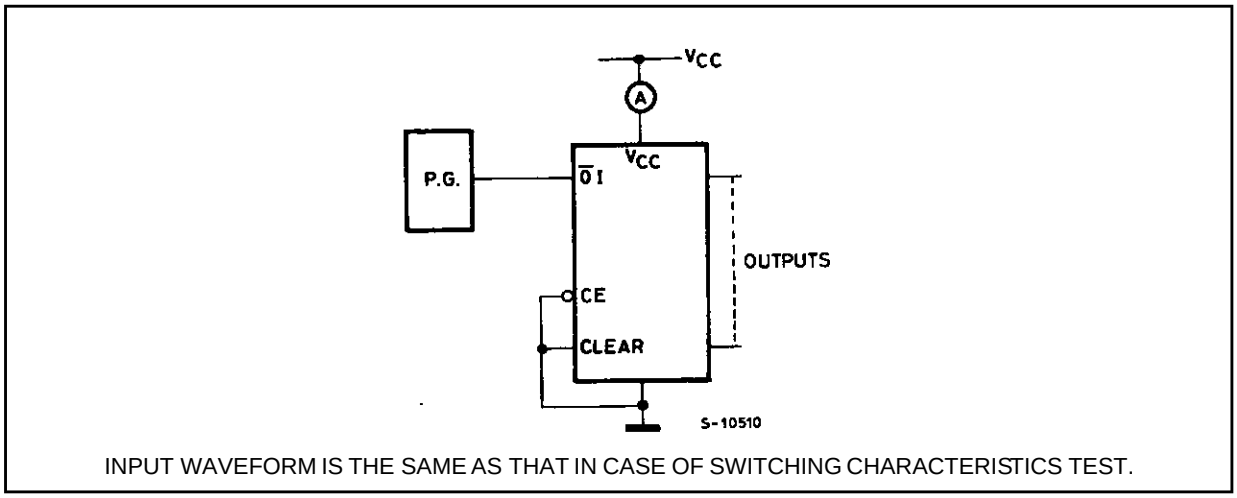
Symbol	Parameter	Test Conditions		Value							Unit
		V_{CC} (V)		T_A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{TLH} t_{THL}	Output Transition Time	2.0			30	75		95		110	ns
		4.5			8	15		19		22	
		6.0			7	13		16		19	
t_{PLH} t_{PHL}	Propagation Delay Time (CK, CE - Q, C_{OUT})	2.0			100	195		245		295	ns
		4.5			25	39		49		59	
		6.0			21	33		42		50	
t_{PLH} t_{PHL}	Propagation Delay Time (CLEAR- Q, C_{OUT})	2.0			100	195		245		295	ns
		4.5			25	39		49		59	
		6.0			21	33		42		50	
f_{MAX}	Maximum Clock Frequency	2.0		5	10		4		3.4		ns
		4.5		25	41		20		17		
		6.0		29	48		24		20		
$t_{W(H)}$ $t_{W(L)}$	Minimum Pulse Width (CLOCK)	2.0			35	75		95		110	ns
		4.5			7	15		19		22	
		6.0			6	13		16		19	
$t_{W(H)}$	Minimum Pulse Width (CLEAR)	2.0			35	75		95		110	ns
		4.5			7	15		19		22	
		6.0			6	13		16		19	
t_s	Minimum Set-up Time	2.0			12	50		65		75	ns
		4.5			3	10		13		15	
		6.0			3	9		11		13	
t_h	Minimum Hold Time	2.0			32	75		95		110	ns
		4.5			8	15		19		22	
		6.0			7	13		16		19	
t_{REM}	Minimum Removal Time	2.0			28	75		95		110	ns
		4.5			7	15		19		22	
		6.0			6	13		16		19	
C_{IN}	Input Capacitance				5	10		10		10	pF
C_{PD} (*)	Power Dissipation Capacitance				41						pF

(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operting current can be obtained by the following equation. $I_{CC}(opr) = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST WAVEFORM



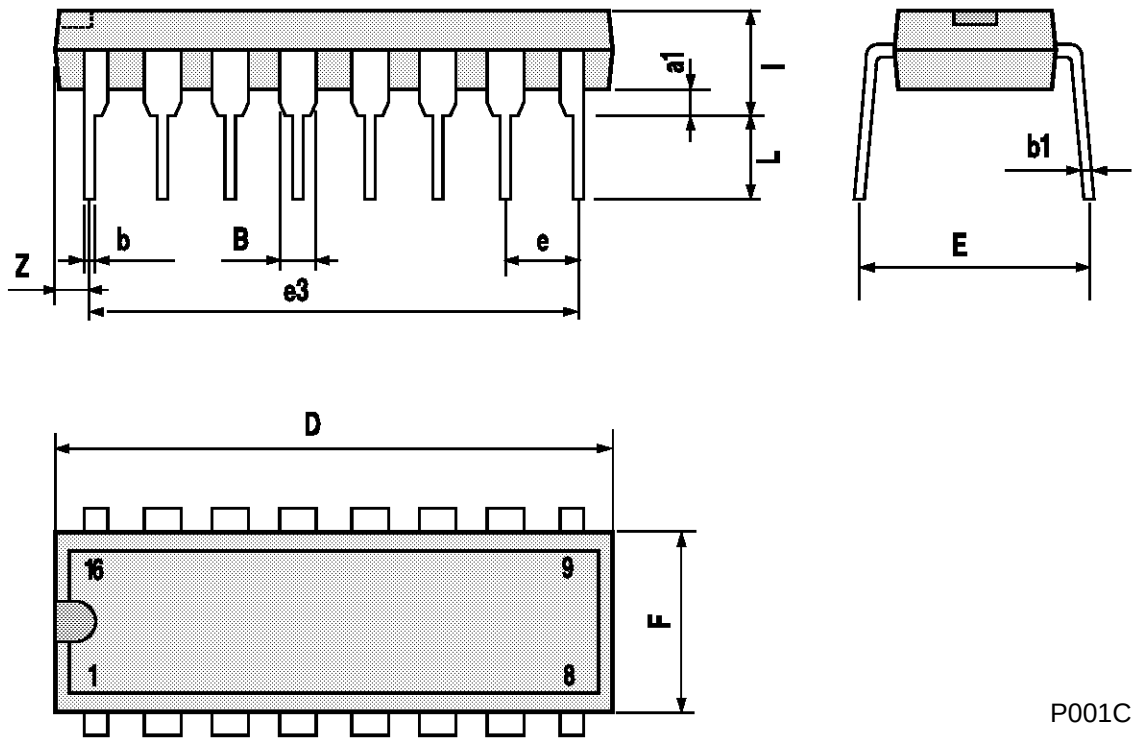
TEST CIRCUIT I_{CC} (Opr.)



INPUT WAVEFORM IS THE SAME AS THAT IN CASE OF SWITCHING CHARACTERISTICS TEST.

Plastic DIP16 (0.25) MECHANICAL DATA

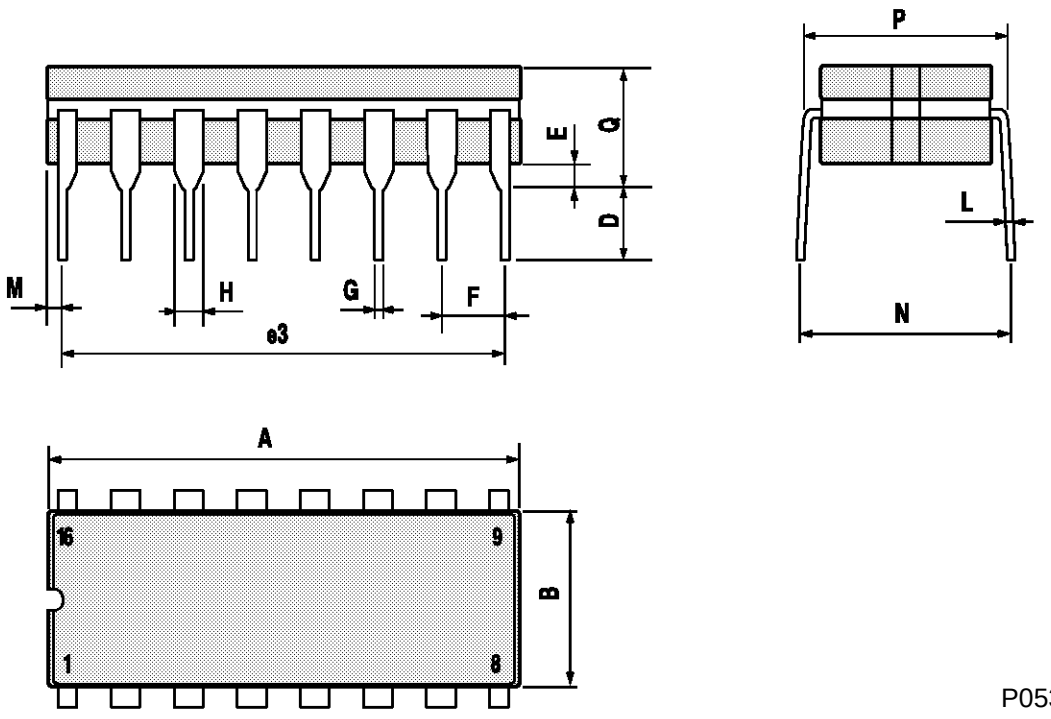
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



P001C

Ceramic DIP16/1 MECHANICAL DATA

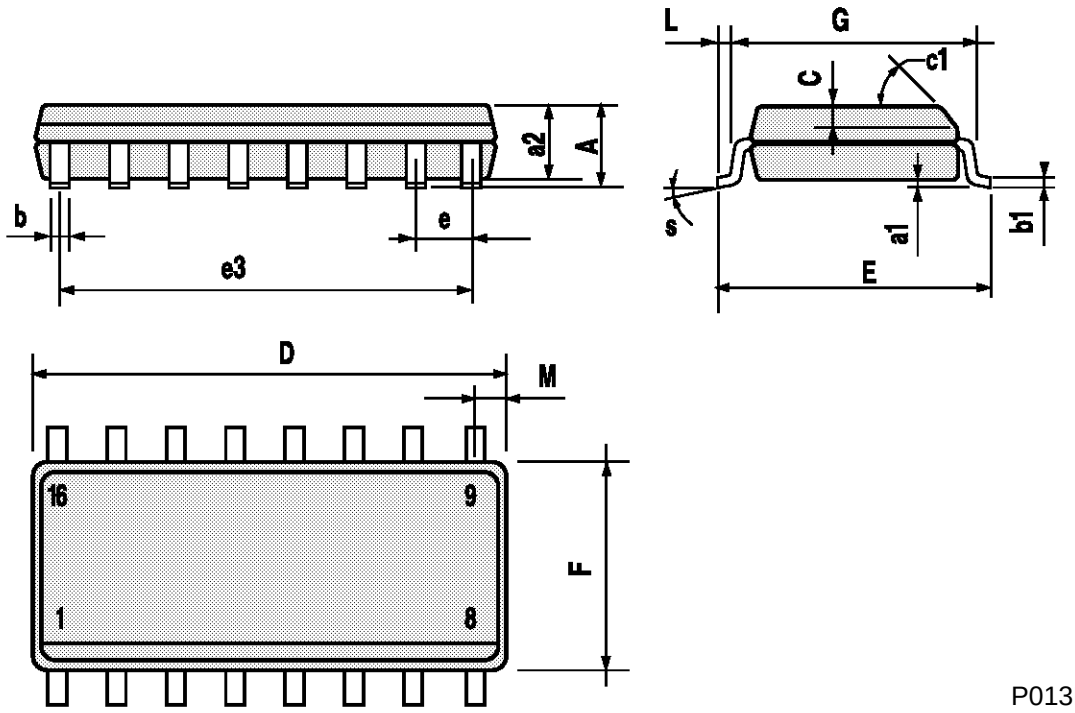
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			20			0.787
B			7			0.276
D		3.3			0.130	
E	0.38			0.015		
e3		17.78			0.700	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
H	1.17		1.52	0.046		0.060
L	0.22		0.31	0.009		0.012
M	0.51		1.27	0.020		0.050
N			10.3			0.406
P	7.8		8.05	0.307		0.317
Q			5.08			0.200



P053D

SO16 (Narrow) MECHANICAL DATA

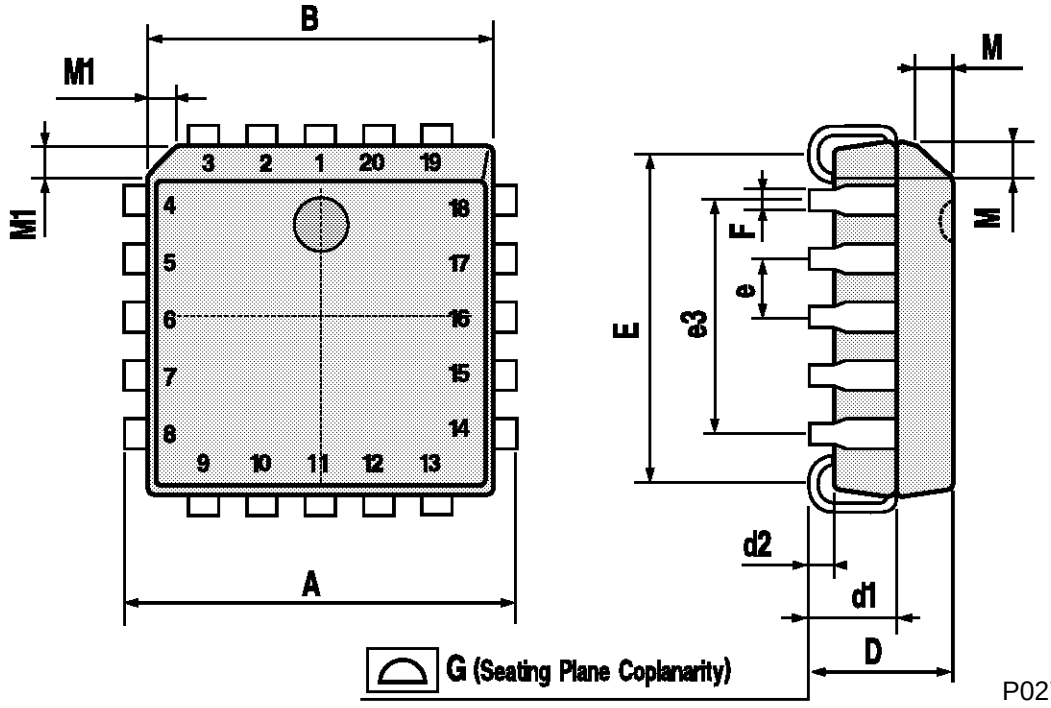
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.004		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					



P013H

PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	



P027A